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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO. CONFIRMATION NO		
09/836,857	04/17/2001	Seiichi Iwamatsu	12179-P098US 5893		
29444 7	7590 01/16/2004		EXAMINER		
KELLY KOR WINSTEAD S	RDZIK ECHREST & MINICK	VANORE, DAVID A			
5400 RENAISSANCE TOWER			ART UNIT	PAPER NUMBER	
DALLAS, TX	75270		2881		
			DATE MAILED: 01/16/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary		Application		Applicant(s)			
		09/836,85		IWAMATSU, SEIICHI			
		Examiner		Art Unit			
	The MAN INC DATE of this communication	David A V		2881	<u> </u>		
Period fo	The MAILING DATE of this communication or Reply	on appears on the	ecover sneet with the c	correspondence ac	idress		
THE I - Exter after - If the - If NO - Failu - Any r	ORTENED STATUTORY PERIOD FOR R MAILING DATE OF THIS COMMUNICATI nsions of time may be available under the provisions of 37 C SIX (6) MONTHS from the mailing date of this communicati period for reply specified above is less than thirty (30) days period for reply is specified above, the maximum statutory re to reply within the set or extended period for reply will, by eply received by the Office later than three months after the department of the set of the se	ION. CFR 1.136(a). In no evolution. s, a reply within the stat period will apply and w a statute, cause the app	ent, however, may a reply be tin utory minimum of thirty (30) day ill expire SIX (6) MONTHS from dication to become ABANDONE	nely filed s will be considered time the mailing date of this o D (35 U.S.C. § 133).			
	Responsive to communication(s) filed on	08 December 2	003				
•	•	This action is no					
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Dispositi	on of Claims	·	•				
4) 🖂	○ Claim(s) 1-9 is/are pending in the application.						
,	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)	5) Claim(s) is/are allowed.						
6)🛛	6)⊠ Claim(s) <u>1-9</u> is/are rejected.						
7)	Claim(s) is/are objected to.						
8)□	Claim(s) are subject to restriction	and/or election r	equirement.				
Applicati	ion Papers						
•	The specification is objected to by the Exa						
10)⊠	The drawing(s) filed on 17 April 2001 is/a	re: a)⊠ accepte	ed or b) ☐ objected to	by the Examiner.			
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
	Replacement drawing sheet(s) including the c						
•	The oath or declaration is objected to by t	ine Examiner. No	ote the attached Office	Action or form P	10-152.		
-	under 35 U.S.C. §§ 119 and 120						
	Acknowledgment is made of a claim for for All b) Some * c) None of: 1. Certified copies of the priority docu 2. Certified copies of the priority docu	ıments have bee ıments have bee	en received. en received in Applicat	ion No			
* ¢	3. Copies of the certified copies of the application from the International Esee the attached detailed Office action for	Bureau (PCT Rul	le 17.2(a)).		Stage		
13) <u> </u>	Acknowledgment is made of a claim for do ince a specific reference was included in t 7 CFR 1.78.	mestic priority u the first sentence	nder 35 U.S.C. § 119(e of the specification o	e) (to a provisiona r in an Applicatior			
14) 🗌 A)	mestic priority u	nder 35 U.S.C. §§ 120	and/or 121 since			
Attachmen	t(s)						
1) X Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-94	48)	4) Interview Summary 5) Notice of Informal F				
	mation Disclosure Statement(s) (PTO-1449) Paper N		6) Other:	atent Application (PT	O-102)		

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DETAILED ACTION

Response to Arguments

In view of the Appeal Brief filed on December 8, 2003, PROSECUTION IS HEREBY REOPENED. A new ground of rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

- (1) file a reply under 37 CFR 1.111 (if this Office action is non-final) or a reply under 37 CFR 1.113 (if this Office action is final); or,
 - (2) request reinstatement of the appeal.

If reinstatement of the appeal is requested, such request must be accompanied by a supplemental appeal brief, but no new amendments, affidavits (37 CFR 1.130, 1.131 or 1.132) or other evidence are permitted. See 37 CFR 1.193(b)(2).

Applicant's arguments filed December 8, 2003 have been fully considered but they are not persuasive.

Applicant's arguments regarding claims 1-3, 6, and 9 are not found to be persuasive.

Applicant argues with respect to claim 1 that some of the emitters of Baylor et al. must be turned off during exposure. Baylor et al. teaches a Col. 7 Lines 53-68 that turnon and turn-off of the entire matrix is accomplished by switching mean 440 and that individual emitter control can be processed by connection 530 to each individual emitter.

Applicant argues with respect to claim 6 that the conductive grid (440) of Baylor et al. not deposited on the substrate. Looking to Fig. 5, grid 440 is clearly deposited on

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the hatched layer which is deposited on substrate 510. Therefore, grids 441-444, which comprise grid 440, are deposited on the substrate.

Applicant's arguments with respect to claims 4, 5, 7, and 8 have been considered but are most in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-4, 6, and 9 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Baylor et al.

Baylor et al. teaches an electron beam lithography apparatus comprising a first substrate (Fig. 5 Item 510) having electron field emitters (431,432,433,434) positioned there above with an electric grid circuit (440) to control the emission of electrons from the desired emitters. Baylor et al. further teaches a second substrate (350) having a resist coating thereon which electron beams are impinged on to form a desired pattern as recited in claim 1. See Baylor et al. (Col. 3 Line 44 – Col. 4 Line 25.)

Wherein the electron emission material is deposited on the first substrate in a predefined pattern (Fig. 5 and Col. 5 Lines 55-68) and where the emission material emits electrons on a continuous basis when activated (Col. 7 Lines 54-68).

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Fig. 5 also clearly shows that there is no emission material in between emitter array elements (431,432,433, etc.).

Regarding claims 2 and 3, Baylor et al. teaches the use of magnetic and electrostatic field lenses (463, 467, 470) between the first and second substrate to focus the electron beams.

Regarding claim 4, Baylor et al. further teaches a conductive layer between the first substrate and the field emitters. The conductive layer (520) controls electron emission.

Regarding claims 6 and 9, Baylor et al. teaches a conductive material deposited on the first substrate between field emitters (441, 442, 443, 444), which is positioned such that the emitter is recessed below the surface of the conductive material.

Regarding the amendment to claim 1, the field emission means (431) are active field emitters disposed on the first substrate in a predefined pattern. Baylor et al. does not indicated that these emitters move, therefore they are positioned on a permanent basis. Further, when a current is applied to said emitters, they continuously emit electrons. Looking to Fig. 5, no active material lies outside the pattern, since it necessarily defines the pattern, meaning that there is a space between boundary material 441 and emitters 431. Since no emission material lies between 431 and 441, no electrons are emitted from this space between them, again see the emission lines coming from 431.

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Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 5 is rejected under 35 U.S.C. 103(a) as being unpatentable over Baylor et al. in view of Park.

Baylor et al. teaches all limitations as applied above but fails to teach a second substrate positioned a distance from the emitter substrate having a conductive layer implanted therein between a substrate layer and a resist layer.

Park teaches a lithography device in which the target of a lithography beam of electron radiation is a second substrate positioned a distance from a field emission means with a layer of conductive material deposited between the second substrate and a layer of resist (Col. 2 Lines 3-28).

Modifying the device of Baylor et al. with the device of Park would produce a field emitting array electron beam lithography device whose target is a wafer having a conductive layer implanted therein between a substrate layer and a resist layer.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to supply a substrate having a conductive layer interposed between a substrate layer and a resist layer because the layering of conductors and resist on a substrate allows the process of semiconductor manufacture to be accomplished where

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an electron beam reacts with the resist, selectively exposing the conductive layer during the development process to allow fabrication of a desired circuit on a substrate.

Claims 7 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Baylor et al.

Baylor et al. teaches all limitations as applied above but fails to teach a conductive material which cover the edges of the field emitter as recited in claim 7 or where the conductive material is coplanar with the emitting surface of the field emitter as recited in claim 8.

Baylor et al. does teach that it is within the level of ordinary skill in the art to provide a conductive layer such as in claim 6 of any shape so long as a suitable emission field is produced (Col. 8 Lines 40-45).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to provide a conductive material which cover the edges of the field emitter as recited in claim 7 or where the conductive material is coplanar with the emitting surface of the field emitter as recited in claim 8 because Baylor et al. teaches that the conductive grid disclosed in the prior art would be fashioned into any desired shape.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David A Vanore whose telephone number is 703-306-0246. The examiner can normally be reached on M-F 7:30-5:00.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John R. Lee can be reached on 703-308-4116. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

dav